NE/SA5234

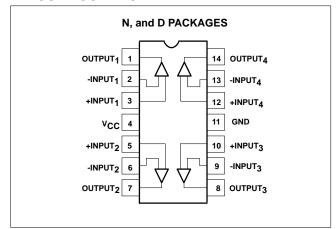
DESCRIPTION

The NE/SA5234 is a matched, low voltage, high performance quad operational amplifier. Among its unique input and output characteristics is the capability for both input and output rail-to-rail operation, particularly critical in low voltage applications. The output swings to less than 50mV of both rails across the entire power supply range. The NE/SA5234 is capable of delivering 5.5V peak-to-peak across a 600 Ω load and will typically draw only 700 μ A per amplifier. The bandwidth is 2.5MHz and the 1% settling time is 1.4 μ s.

FEATURES

- Wide common-mode input voltage range: 250mV beyond both rails
- Output swing within 50mV of both rails
- Functionality to 1.8V typical
- Low current consumption: 700µA per amplifier
- ±15mA output current capability
 Unity gain bandwidth: 2.5MHz
- Slew rate: 0.8V/µs
 Low noise: 25nV/√Hz
- Electrostatic discharge protection
- Short-circuit protection
- Output inversion prevention

PIN CONFIGURATION



APPLICATIONS

- Automotive electronics
- Signal conditioning and sensing amplification
- Portable instrumentation
 - Test and measurement
 - Medical monitors and diagnostics
 - Remote meters
- Audio equipment
- Security systems
- Communications
 - Pagers
 - Cellular telephone
 - LAN
 - 5V Datacom bus
- Error amplifier in motor drives
- Transducer buffer amplifier

ORDERING INFORMATION

DESCRIPTION	TEMPERATURE RANGE	ORDER CODE	DWG #
14-Pin Plastic Small Outline (SO) package	0 to +70°C	NE5234D	0175D
14-Pin Plastic Dual In-Line Package (DIP)	0 to +70°C	NE5234N	0405B
14-Pin Plastic Small Outline (SO) package	-40 to +85°C	SA5234D	0175D
14-Pin Plastic Dual In-Line Package (DIP)	-40 to +85°C	SA5234N	0405B

NE/SA5234

ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNITS
V _{CC}	Single supply voltage	7	V
V _{ESD}	ESD protection voltage at any pin ⁵ human body model robot model	2000 200	V
V _S	Dual supply voltage	<u>+</u> 3.5	V
V_{DP}	Voltage at any device pin ¹	V _S <u>+</u> 0.5	V
I _{DP}	Current into any device pin ¹	<u>+</u> 50	mA
V _{IN}	Differential input voltage ²	0.5	V
V _{CM}	Common-mode input voltage (positive)	V _{CC} + 0.5	V
V _{CM}	Common-mode input voltage (negative)	V _{EE} - 0.5	V
P_{D}	Power dissipation ³	500	mW
TJ	Operating junction temperature ³	+150	°C
V _{SC}	Supply voltage allowing indefinite output short circuit to either rail ^{3,4}	7	V
T _{STG}	Storage temperature range	-65 to +150	°C
T _{SOLD}	Lead soldering temperature (10sec max)	+300	°C
θ_{JA}	Thermal impedance		
	14 pin Plastic DIP	80	°C/W
	14 pin Plastic SO	115	°C/W

NOTES:

- 1. Each pin is protected by ESD diodes. The voltage at any pin is limited by the ESD diodes.
- 2. The differential input of each amplifier is limited by two internal diodes, connected in parallel and opposite to each other. For more differential input range, use differential resistors in series with the input pins.
- 3. The maximum operating junction temperature is +150°C. At elevated temperatures, devices must be derated according to the package thermal resistance and device mounting conditions. Derates above +25°C: F package at 6.7mW/°C; N package at 9.5mW/°C; D package at 6.25mW/°C.
- 4. Simultaneous short circuits of two or more amplifiers to the positive or negative rail can exceed the power dissipation ratings and cause eventual destruction of the device.
- 5. Guaranteed by design.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	RATING	UNITS
V _{CC}	Single supply voltage	+2 to +5.5	V
Vs	Dual supply voltage	<u>+</u> 1 to <u>+</u> 2.75	V
V _{CM}	Common-mode input voltage (positive)	V _{CC} + 0.25	V
V _{CM}	Common-mode input voltage (negative)	V _{EE} - 0.25	V
T _A	Temperature		
	NE	0 to +70	°C
	SA	-40 to +85	°C

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DC ELECTRICAL CHARACTERISTICS

 V_{CC} = 2 to 5.5V, V_{EE} = 0V, T_A = 25°C; V_{EE} < V_{CM} < V_{CC} ; unless otherwise stated.

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS						_
			NE5234			SA5234			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	1
		V _{CC} = 5.5V		2.8	4.0		2.8	4.0	
I _{CC}	Supply current	V _{CC} = 5.5V over full temperature range		3.0	4.6		3.2	4.8	mA
				±0.2	±4		±0.2	±4	
V _{OS}	Offset voltage	Over full temperature range		±0.4	±5		±0.6	±5	mV
ΔV _{OS} /ΔT	Offset voltage drift with temperature			4			4		μV/°C
	Offset voltage difference			0.4	3		0.4	3	
ΔV_{OS}	between any amplifiers in the same package at the same common mode level ¹	Over full temperature range		0.8	4		1.2	4	mV
				±3	±20		±3	±30	
los	Offset current	Over full temperature range		±4	±30		±6	±60	nA
ΔΙ _{ΟS} /ΔΤ	Offset current drift with temperature			0.02	±.3		0.03	±.3	nA/°C
I _B	Input bias current ¹	$V_{EE} < V_{CM} < V_{EE} + 0.5V$	-200	-90		-200	-90		nA
		Over full temperature range	-225	-100		-250	-150		
		V_{EE} +1V < V_{CM} < V_{CC}		25	70		25	75	
		Over full temperature range		35	100		35	120	
$\Delta I_{B}/\Delta T$	Input bias current drift with temperature			0.5			0.5		nA/°C
	Input bias current difference between any amplifier in the same package at the same	$V_{EE} < V_{CM} < V_{EE} +0.5V$		10	30		10	30	
Δl_{B}		Over full temperature range		25	50		50	70	nA
	common mode level.	V_{EE} +1V < V_{CM} < V_{CC}		5	20		5	20	1
		Over full temperature range		15	30		25	50	
.,		V _{OS} ≤ 6mV	V _{EE} -0.25		V _{CC} +0.25	V _{EE} -0.25		V _{CC} +0.25	J .,
V _{CM}	Common-mode input range	V _{OS} ≤ 6mV over full temperature range	V _{EE} -0.1		V _{CC} +0.1	V _{EE} -0.1		V _{CC} +0.1	V
	Common-mode rejection ratio, small signal	$V_{EE} < V_{CM} < V_{EE} + 0.5V,$ $V_{EE} + 1V < V_{CM} < V_{CC}$		100		90	100		
CMRR		Over full temperature range		100		80	90		dB
	Common mode rejection	V _{EE} < V _{CM} < V _{CC}		90			100		
	Common-mode rejection ratio, large signal	Over full temperature range		80			90		
		$V_{EE} < V_{CM} < V_{CC}$	80	100		80	100		
PSRR	Power supply rejection ratio	Over full temperature range	80	90		80	90		dB

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DC ELECTRICAL CHARACTERISTICS (continued)

	PARAMETER		LIMITS						
SYMBOL		TEST CONDITIONS	NE5234			SA5234			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	1 1
	Poak load current sink and		10	12		10	12		
I _L Peak load current, sink and source	Over full temperature range	5	8		5	8		mA	
A _{VOL} Open-loop voltage gai			90	110		90	110		
	Open-loop voltage gain	Over full temperature range		90			90		dB
Vouт	Output voltage swing	I _{PEAK} = 0.1mA	V _{EE} +0.0 5		V _{CC} -0.05	V _{EE} +0.1		V _{CC} -0.1	V
		I _{PEAK} = 10mA	V _{EE} +0.2 5		V _{CC} -0.25	V _{EE} +0.2 5		V _{CC} -0.25	
		I _{PEAK} = 5mA over full temp range	V _{EE} +0.2 2		V _{CC} -0.2	V _{EE} +0.2		V _{CC} -0.2	
	Output voltage swing for V _{CC} = 2.75V, V _{EE} = -2.75V	$R_L = 2k\Omega$	V _{EE} +0.2		V _{CC} -0.2	V _{EE} +0.2		V _{CC} -0.2	
		$R_L = 600\Omega$,	V _{EE} +0.2 5		V _{CC} -0.25	V _{EE} +0.2 5		V _{CC} -0.25	V

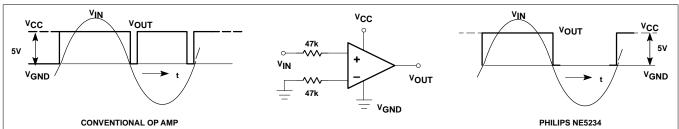
NOTES

AC ELECTRICAL CHARACTERISTICS

 T_A = +25°C; V_{CC} = 2 to 5.5V; R_L = 10k; C_L = 100pF; unless otherwise stated.

	PARAMETER	TEST CONDITIONS	LIMITS						
SYMBOL			NE5234			SA/SE5234			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	1
SR	Slew rate	Over full temperature range	0.5	0.8		0.5	0.8		V/µs
BW	Unity gain bandwidth: -3dB	Over full temperature range	2	2.5	4.0	2	2.5	4.0	MHz
θ_{M}	Phase Margin	$C_L = 50pF$		55			55		deg
ts	1% settling time	A _V = 1, 1V step		1.4			1.4		μs
V _N	Input referred voltage noise	$A_V = 1$, $R_S = 0Ω$, at 1kHz		25			25		nV/Hz 1/2
THD	Total harmonic distortion	$10kHz, 1V_{P-P}, A_V = 1$		0.1			0.1		%

OUTPUT INVERSION PREVENTION



These parameters are measured for V_{EE} < V_{CM} < V_{EE}+.5V and for V_{EE}+1V < V_{CM} < V_{CC}. By design these parameters are intermediate for common mode ranges between the measured regions.